

(2) Code No. : B-267(B)

Roll No.....

Total No. of Questions : 05

Total No. of Printed Pages : 04

Explain the principle of feedback transistor oscillators and Barkhausen Criteria.

(r) $\frac{1}{\beta} \frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$

Describe the circuit and working of Hartley oscillator. Hence obtain an expression for its frequency.

Unit-V

ZaTAA-5. $\frac{1}{\beta} \frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$

(i) $\frac{1}{\beta} \frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$

(r) $\frac{1}{\beta} \frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$

Write short notes on :

- (a) Memory and its various types
- (b) Multi programming and time sharing systems

OR

ZaamDnaqAA avao yç uaqmi ytaSyE1/a Sya Nv Oaam SyEAAç Sy av¥ C Zaçaat avah¥ ñ

Write a C-Programme to solve simultaneous equations by elimination method.

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Annual Examination - 2017

B.Sc.-III

PHYSICS

Paper-II

SOLID STATE PHYSICS, SOLID STATE DEVICES

AND ELECTRONICS

Max.Marks : 50

Time : 3 Hrs.

Min.Marks : 17

$\frac{1}{\beta} \frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$

Note : Attempt one question from each unit. All questions carry equal marks.

Unit-I

ZaTAA-1. $\frac{1}{\beta} \frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$ $\frac{d\beta}{d\omega} \gg 1$

Describe the method to determine Miller Indices for a crystal plane. Obtain a formula to determine perpendicular distance between two crystal planes in a cubic crystal. Draw (100) and (110) planes for a simple cubic crystal.

P.T.O.

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OR

- ybOalm a'iq/aa avahf B
- (j) rbaa rvapSj ; aof qE o'p'apSja w'alSjE/a
- (r) f'c' y - aSjE/a amwma Sj vaE y ay ÷ am

Write short notes on :

- (a) Classification of solids based on binding forces
- (b) Laue's theory of X-ray diffraction

Unit-II

ZaTaa-2. oamj aptetdy cvc' 1pa tapv Sj luaua Sylakf n cySyl yAvmaYf mna ; yAvmaYf EAaNE/a yalm ytl acf mna cySyl ta' SjatuaSja w/aa Sylakf n

Describe the free electron model of metals. Explain its success and failure giving suitable examples. State basic drawbacks of this model.

OR

- (j) Zaa'j arSylu, ; Aaj arSylu mna vaal j arSylu qaanaatp ; mE Dq~p Sylakf n
- (r) Zaa'j arSylu qaanaatSj avf vkaava Sj aj EyEtm ay ÷ am ytl amcNE' caaSyl j arSylu Zavaa Sj avf luukSj Zaam SjEen

Describe the classical theory of Langevin for diamagnetic substance. Hence obtain an expression for their magnetic susceptibility.

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Unit-III

ZaTaa-3. yho »puapSj avf wad 1ma- oEa yErao ; naani »puapSj taSjE/a Zaam Sylakf mna cySj ; aof qE »puapSj ; asvaOaa/Sj wSjap Syl luaua Sylakf n

Obtain the current-voltage relation i.e. diode equation for a junction diode. Hence explain the characteristic curves of diode using diode equation.

OR

ZaTaa-3. E3/kSj »puap Syl Ej Aaa, ay ÷ am, Sjaavao mna Equata ytl acf n

Explain the construction, principle, working and application of Light Emitting Diodes .

(H.E.N.)

Unit-IV

ZaTaa-4. j ÷ enE'a aA' SjafEa mna qaamEpa aA' SjafEa Sj ma'aa afaaa arAa ap Sj j aof qE Sylakf B

- (j) avum qafqn (r) SjausjafEa ay ÷ am
- (y) EatSja i' Sj (A) Aaama

Compare half wave rectifier and full wave rectifier based on the following points :

- (a) Circuit diagram (b) Working principle
- (c) Ripple factor (d) Efficiency

OR

(j) qaanaatvda Aavda Sj ay ÷ am w rEhaSja Sjyaepi Sj luaua Sylakf n